

KSC2330A

Color TV Chroma Output

- Collector-Base Voltage: V_{CBO}=400V
 Current Gain Bandwidth Product: f_T=50MHz (TYP.)



1. Emitter 2. Collector 3. Base

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{CBO}	Collector-Base Voltage	400	V
V _{CEO}	Collector-Emitter Voltage	400	V
V _{EBO}	Emitter-Base Voltage	7	V
I _C	Collector Current	100	mA
P _C	Collector Power Dissipation	1	W
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ +150	°C

Electrical Characteristics T_a =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C=100\mu A, I_E=0$	400			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C=5mA$, $I_B=0$	400			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E=100\mu A, I_C=0$	7			V
I _{CBO}	Collector Cut-off Current	V _{CB} =200V, I _E =0			0.1	μΑ
h _{FE}	DC Current Gain	V _{CE} =10V, I _C =20mA	40		80	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =10mA, I _B =1mA			0.5	V
f _T	Current Gain Bandwidth Product	V _{CE} =30V, I _C =10mA		50		MHz
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0, f=1MHz		4		pF

h_{FE} Classification

Classification	R	0	
h _{FE}	40 ~ 65	55 ~ 80	

Typical Characteristics

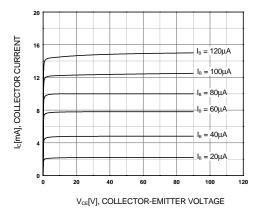


Figure 1. Static Characteristic

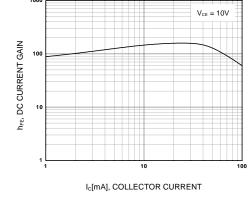


Figure 2. DC current Gain

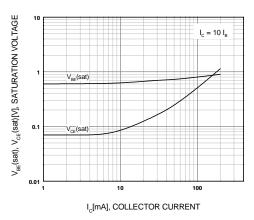


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

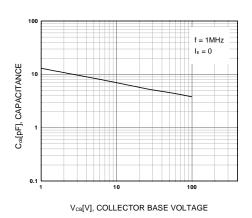


Figure 4. Collector Output Capacitance

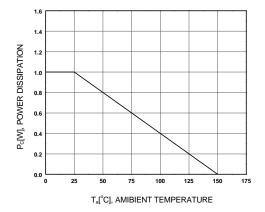
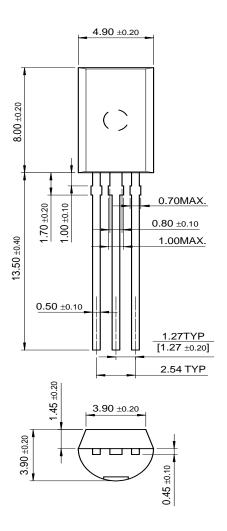


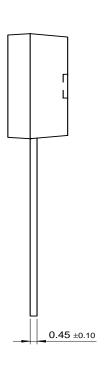
Figure 5. Power Derating



Package Dimensions

TO-92L





Dimensions in Millimeters

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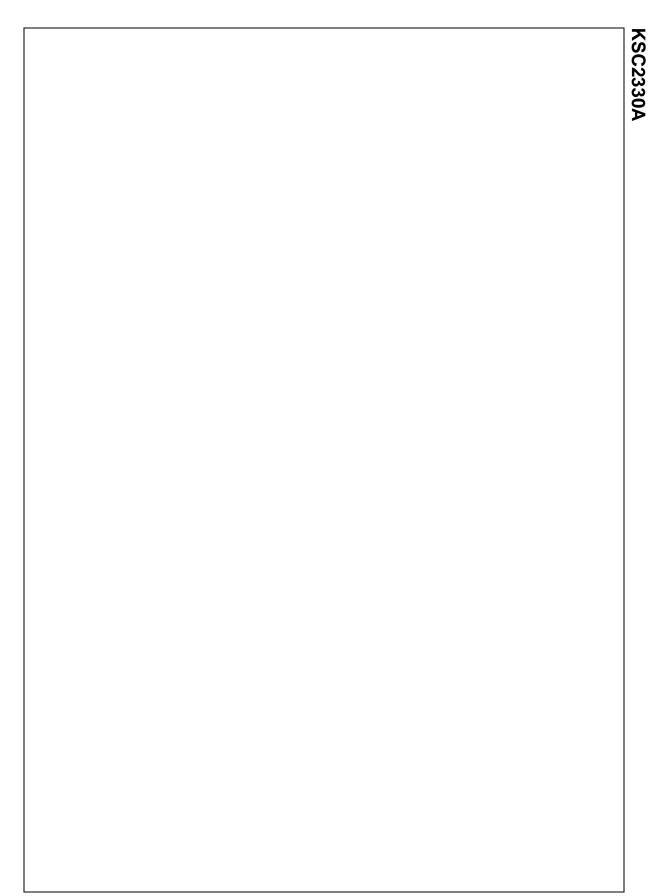
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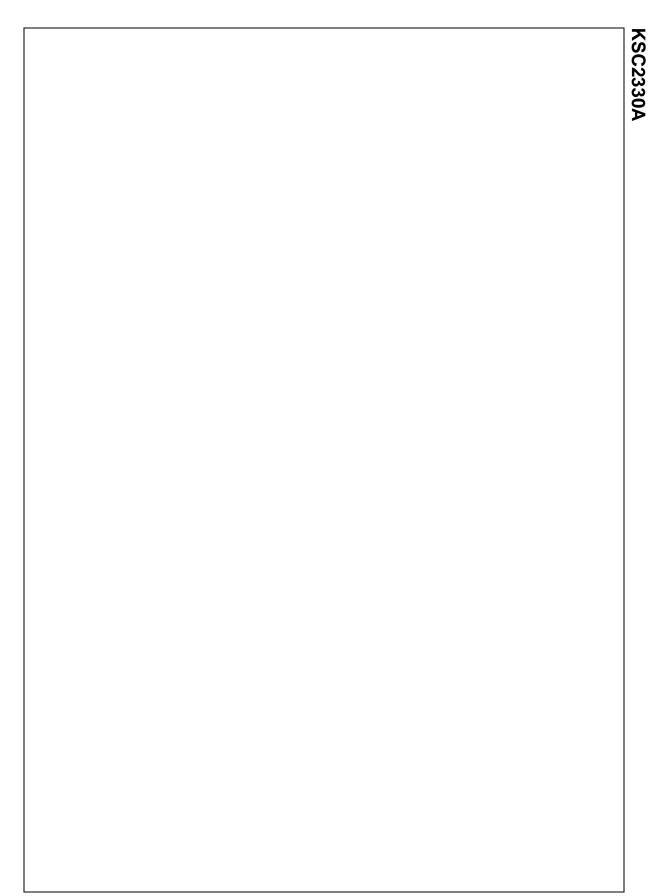
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